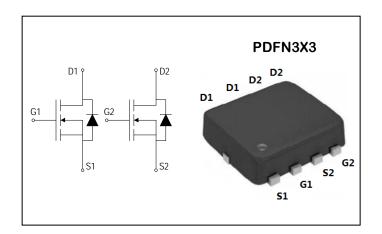


Dual N-Channel Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY

V _{DSS}	ID	$R_{DS(ON)}$ (m Ω)
30V	35A	13m Ω



Absolute Maximum Ratings (TA = 25°C unless otherwise specifed)

Symbol	Parameter	Ratings	Unit		
Common F	Ratings				
V _{DSS}	Drain-Source Voltage		30	\ /	
V _{GSS}	Gate-Source Voltage		±20	V	
TJ	Maximum Junction Temperature		150	°C	
Tstg	Storage Temperature Range	nperature Range		°C	
ls	iode Continuous Forward Current Tc=25°C		35	А	
Mounted o	n Large Heat Sink	·			
lом	300μs Pulse Drain Current Tested(1)	T _C =25°C	140	А	
lσ	Continuous Drain Current	T _C =25°C	T _C =25°C 35		
Pb	Maximum Power Dissipation		20	W	

^{1.} Pulse width limited by maximum junction temperature.

Thermal Characteristics

Symbol	Parameter	Ratings	Unit
RthJC	Thermal resistance junction-case max	6.2	°C/W
RthJA	Thermal resistance junction-ambient max	45	°C/W



ADM35ND03Z

Electrical Characteristics (TA=25°C Unless Otherwise Noted)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit	
On/off Charac	teristics						
BVDSS	Drain-Source Breakdown Voltage	V _{GS} =0V, I _{DS} =250uA	30			V	
Inss	Zero Gate Voltage Drain Current	V _{DS} = 30V, V _{GS} =0V T _J =25°C			1.0	uA	
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =250uA	1.3	1.9	2.4	V	
Igss	Gate Leakage Current	V_{GS} = $\pm20V$, V_{DS} = $0V$			±100	nA	
Б	Drain-SourceOn-stateResistance(2)	V _{GS} = 10V, I _{DS} =20A		10	13		
Rds(on)		V _{GS} = 4.5V, I _{DS} =10A		14	18	mΩ	
Dynamic Chara	cteristics						
Ciss	Input Capacitance	V _{GS} =0V,		880			
Coss	Output Capacitance	V _{DS} = 15V,		140		pF	
Crss	Reverse Transfer Capacitance	Frequency=1.0MHz		110		1	
Switching Char	acteristics				•		
td(ON)	Turn-on Delay Time(1)	V _{DD} =15V,		6			
tr	Turn-on Rise Time(1)	I _D = 20A, V _{GS} = 10V,		5			
td(OFF)	Turn-off Delay Time(1)	R _{GEN} =3 Ω		25		ns	
tf	Turn-off Fall Time(1)			7			
Qg	Total Gate Charge(1)	V _{DS} =15V, V _{GS} = 10V,		19			
Qgs	Gate-Source Charge(1)	I _{DS} =20A		4.3		nC	
Qgd	Gate-Drain Charge(1)			6.5			
Avalanche Cha	aracteristics						
FA0	Cingle Dules Avelende Fraggy (3)	L=0.5mH ,Vgs=10V,Rg=25	16		mJ		
EAS	Single Pulse Avalanche Energy (3)	Ω, IAS=8A TJ=25°C					
Diode Charact	eristics					•	
VsD	Diode Forward Voltage(2)	I _{SD} = 20A, V _{GS} = 0 ,T _J =25°C			1.2	V	
trr	Reverse Recovery Time	1 004 41 /11 4004/		7		ns	
Q rr	Reverse Recovery Charge	I _{SD} =20A, dI _{SD} /dt=100A/μs		6.3		nC	

NOTES:

- 1. Surface Mounted on FR4 Board, $t \le 10$ sec.
- 2.The data tested by pulsed , pulse width $\,\leq\,\,300\text{us}$, duty cycle $\,\leq\,\,2\%$
- 3.The Min. value is 100% EAS tested guarantee.



Typical Performance Characteristics

Figure 1: On-Region Characteristics

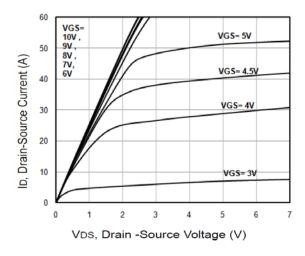


Figure 3: Typical Transfer Characteristics

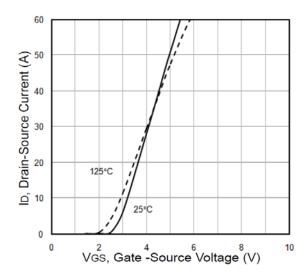


Figure 5: Threshold Voltage Vs. Temperature

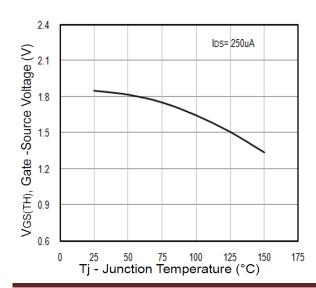


Figure 2: Normalized On-Resistance Vs. Temperature

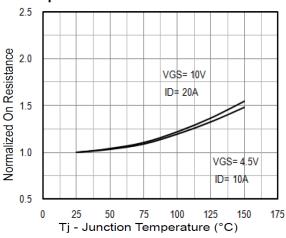


Figure 4: Gate Charge Waveform

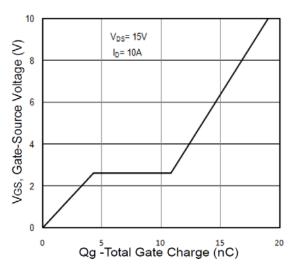


Figure 6: Maximum Safe Operation Area

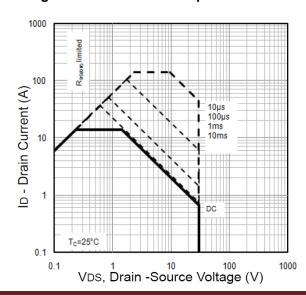




Figure 7: Capacitance vs Vds

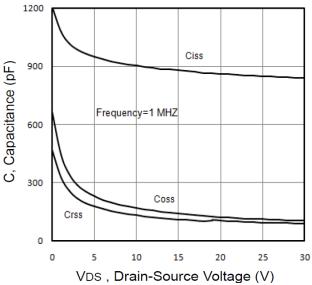
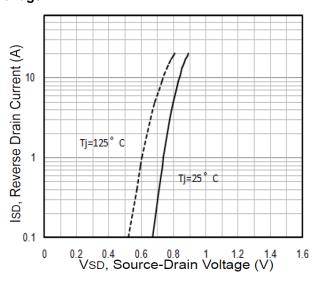


Figure 9: Effective Transient Thermal Response Curve

Figure 8: Typical Source-Drain Diode Forward Voltage



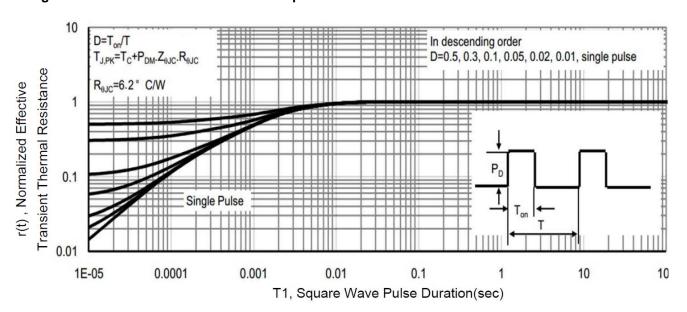


Figure 10: Switching Time Waveform

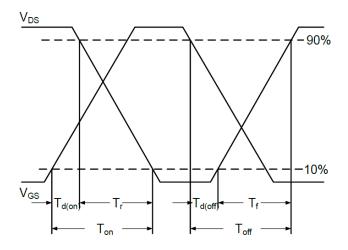
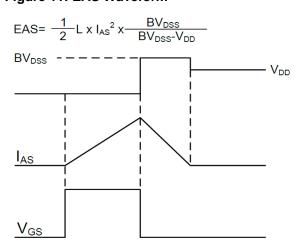


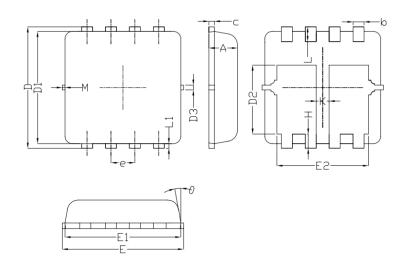
Figure 11: EAS Waveform







PACKAGE MECHANICAL DATA PDFN (3X3) Package Dimension



Symb	Dimensions In Millimeters		Dimensions In Inches	
ol	Min.	Max.	Min.	Max.
Α	0.700	0.800	0.028	0.031
b	0.250	0.350	0.010	0.013
С	0.100	0.250	0.004	0.009
D	3.250	3.450	0.128 0.13	
D1	3.000	3.200	0.119 0.12	
D2	1.780	1.980	0.070	0.077
D3	0.130	REF	0.005REF	
E	3.200	3.400	0.126	0.133
E1	3.000	3.200	0.119	0.125
E2	2.390	2.590	0.094	0.102
Н	0.300	0.500	0.011	0.019
М	0.150REF		0.006REF	
е	0.650 TYP.		0.026 TYP.	
L	0.300	0.500	0.011	0.019
L1	0.130REF		0.005REF	
K	0.300		0.011	
θ	0°	12°	0°	12°

Ordering information

Part number	Package	Marking	Packing	Quantity
ADM35ND03Z	PDFN3*3	M35ND03	Embossed tape	5000pcs



ADM35ND03Z

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